



### 100V P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
-100V	4.2Ω @ V <sub>GS</sub> = -10V	-0.27A
-1007	5.0Ω @ V <sub>GS</sub> = -4.0V	-0.24A

## **Description**

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

## **Applications**

- **DC-DC Converters**
- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.





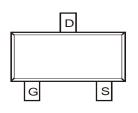
Top View

### **Features and Benefits**

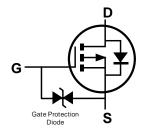
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package ESD Protected up to 2KV (HBM)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Top View Pin Configuration



**Equivalent Circuit** 

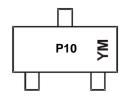
### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP10H4D2S-7	SOT23	3,000/Tape & Reel
DMP10H4D2S-13	SOT23	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



P10 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Kev

Year	2015		2016	2017		2018	2019		2020	2021		2022
Code	С		D	Е		F	G		Н			J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Downloaded From Oneyac.com

May 2017 © Diodes Incorporated



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-100	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-0.27 -0.21	А
Pulsed Drain Current (10µs Pulse, Duty Cycle ≤1%)	I <sub>DM</sub>	-1.0	Α		
Maximum Body Diode Continuous Current (Note 6)	Is	-0.42	А		

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Total Power Dissipation		(Note 5)	ס	0.38	W	
Total Power Dissipation		(Note 6)	$P_D$	0.44	VV	
Thermal Resistance, Junction to Ambient	al Resistance, Junction to Ambient Steady		$R_{\theta JA}$	333		
Thermal Resistance, Junction to Ambient State		(Note 6)	$R_{ heta JA}$	282	°C/W	
Thermal Resistance, Junction to Case		(Note 6)	$R_{ heta JC}$	115		
Operating and Storage Temperature Range			$T_{J_i}T_{STG}$	-55 to +150	°C	

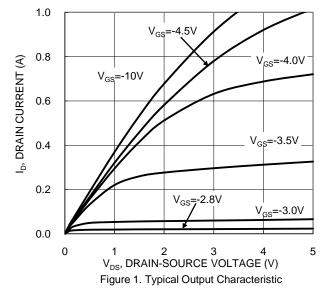
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

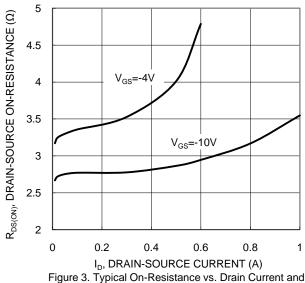
Ziodi idai dilai doto idai de ima izo o, amo							
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-100	—	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	1	μΑ	$V_{DS} = -100V, V_{GS} = 0V$	
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(TH)}$	-1.0	-2.3	-3.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	2.8	4.2	Ω	$V_{GS} = -10V, I_D = -0.5A$	
Static Brain-Source On-Resistance	R <sub>DS(ON)</sub>		3.2	5.0	32	$V_{GS} = -4.0V, I_D = -0.1A$	
Diode Forward Voltage	$V_{SD}$		-0.82	-1.3	V	$V_{GS} = 0V, I_{S} = -0.2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	87			V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	5.6	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	2.9				
Gate Resistance	R <sub>G</sub>	_	15.3	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	_	1.8	_			
Gate-Source Charge	Q <sub>gs</sub>	_	0.3	_	nC	$V_{DS} = -80V, V_{GS} = -10V,$	
Gate-Drain Charge	$Q_{gd}$	_	0.5	_		$I_D = -0.5A$	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.3	_			
Turn-On Rise Time	t <sub>R</sub>	_	2.6	_	no	$V_{DS} = -50V, I_{D} = -0.5A,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		8.4		ns	$V_{GS} = -10V$ , $R_G = 10\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	—	4.9	_			
Reverse Recovery Time	t <sub>RR</sub>		17.8	_	ns	V <sub>R</sub> = -100V, I <sub>F</sub> = -1.0A,	
Reverse Recovery Charge	Q <sub>RR</sub>	_	24.8	_	nC	di/dt = 100A/µs	

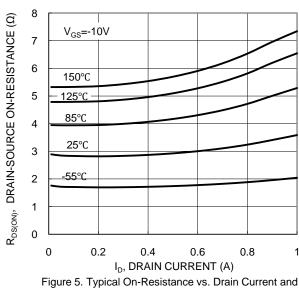
Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- Device mounted on FR-4 substrate PC board, 202 copper, with 1inch square copper pad layout.
  Short duration pulse test used to minimize self-heating effect.
  Guaranteed by design. Not subject to production testing.



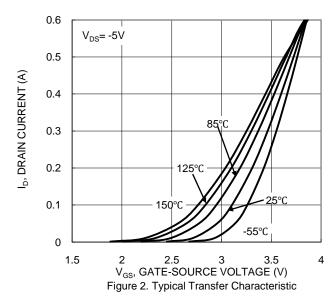


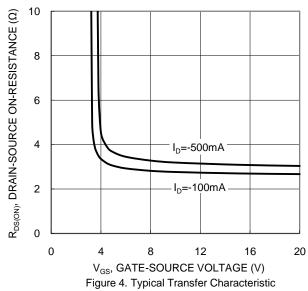




Gate Voltage

Junction Temperature





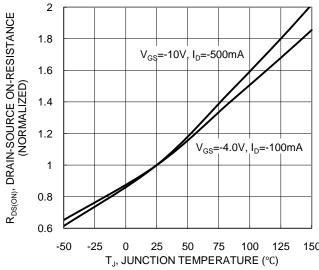
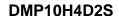
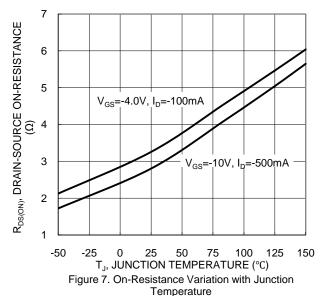
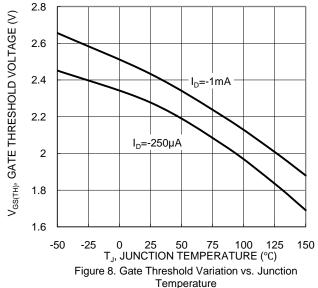


Figure 6. On-Resistance Variation with Junction Temperature



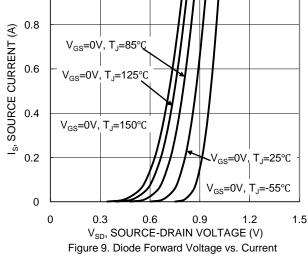


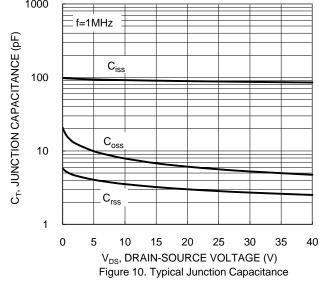


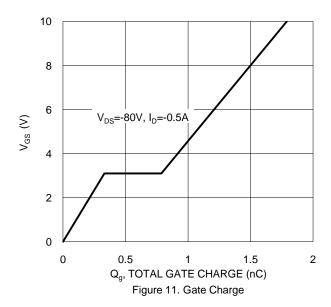


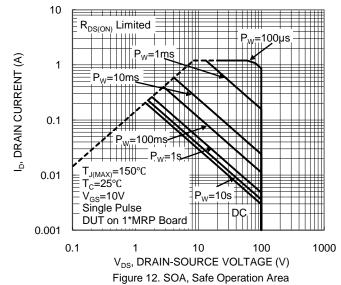
1 0.8  $V_{GS}=0V, T_J=85^{\circ}$ 0.6 /<sub>GS</sub>=0V, T<sub>J</sub>=125°C

1000 f=1MHz

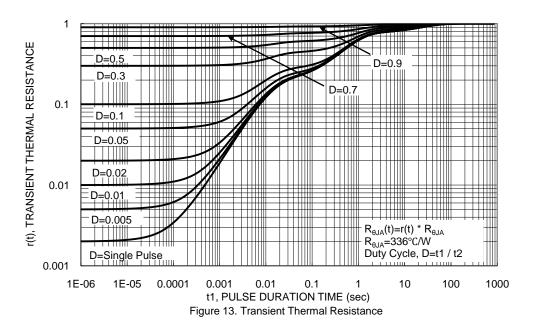








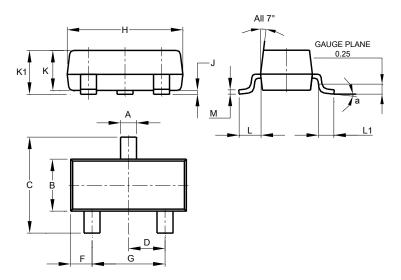




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



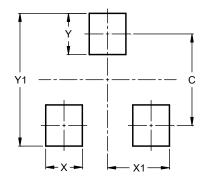
SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							



### Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND. EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT. INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2017, Diodes Incorporated

www.diodes.com

6 of 6 DMP10H4D2S May 2017 Document number: DS37891 Rev. 3 - 2

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达尔科技)